

KID-Based Phonon-Mediated DM Detectors

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Snowmass Quantum Sensors Info Session

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w/NEXUS-FNAL group and LBNL QIS program

Why sense phonons with kinetic inductance detectors (KIDs)?

Energy resolution:
sub-eV \rightarrow meV
thresholds w/o HV

Direct sensitivity to
pair-breaking phonons

Large resonators obviate
qp trapping

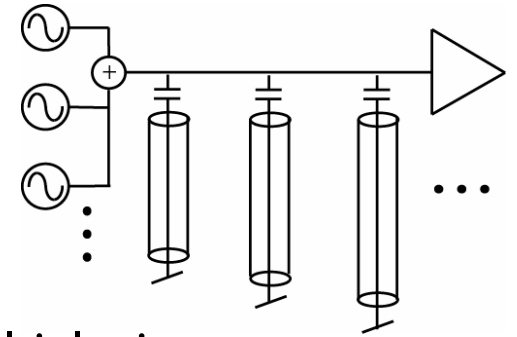
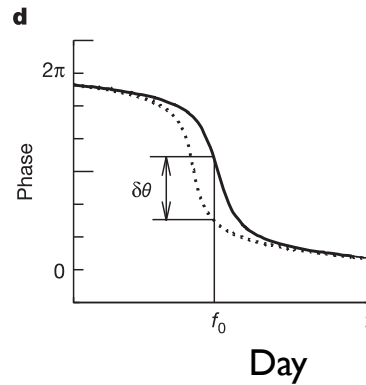
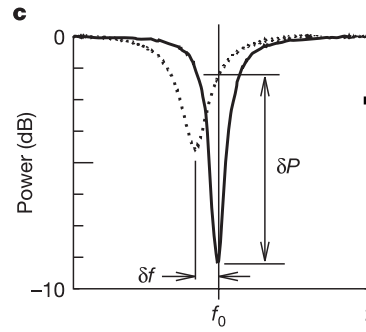
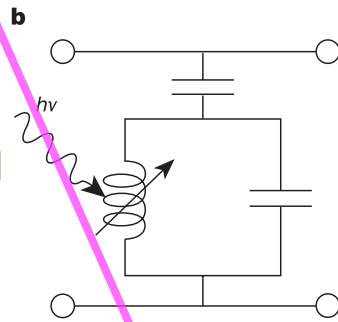
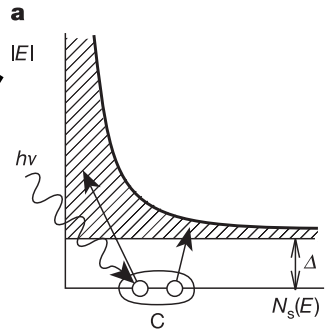
Gapped density of states

Thermal qp population
exponentially suppressed

Fundamentally non-
dissipative

Noise is limited by

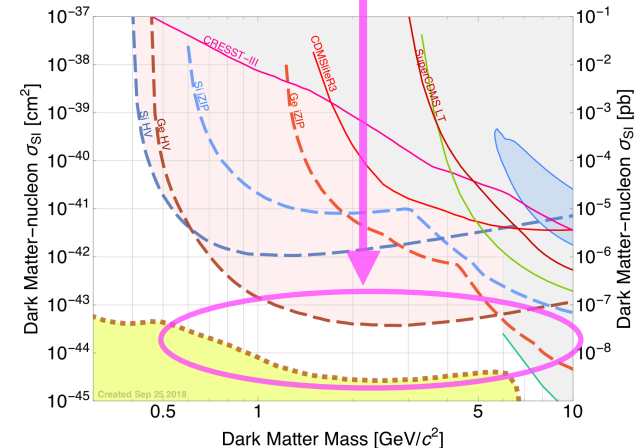
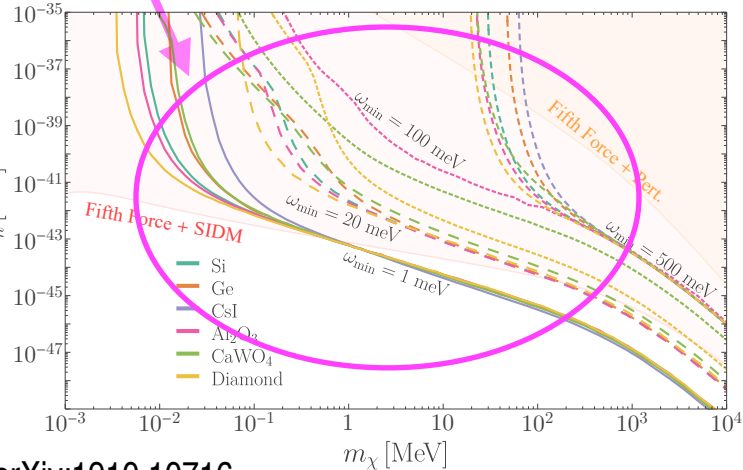
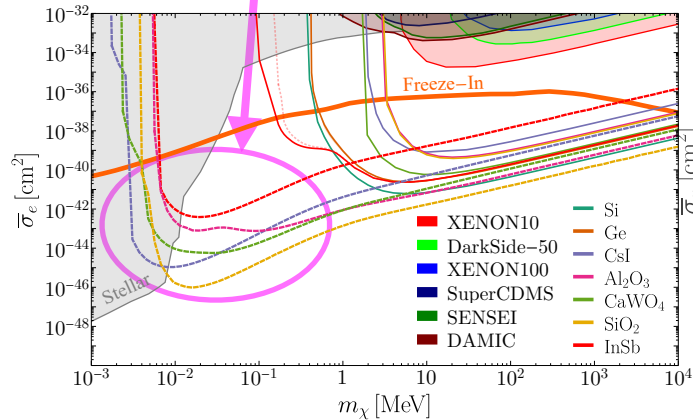
qp population fluctuations
amplifier noise



Multiplexing:

Highly position-resolved
phonon detection
 \rightarrow NR/ER discrimination,
position fiducialization

KIDs are $Q > 10^5$ resonators
 \rightarrow Readout many with one
cryo line/amplifier; most
electronics at 300K

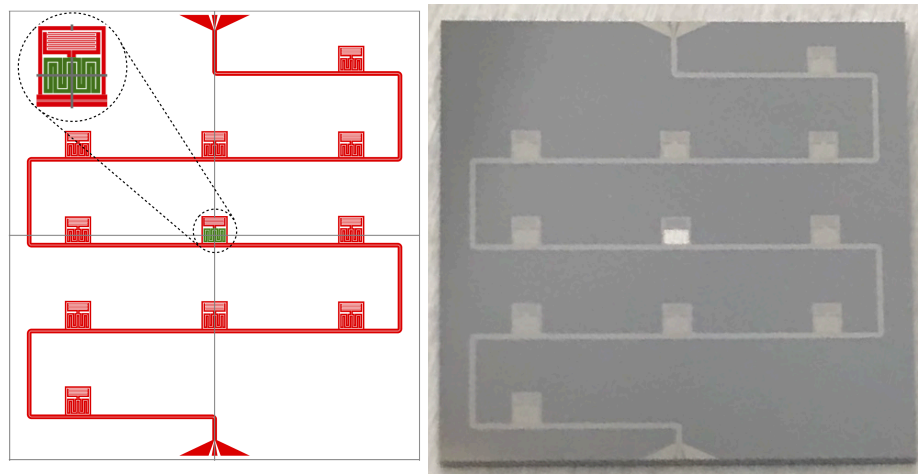


+ dark photons, ALPs, etc. Griffin et al. arXiv:1910.10716

Two Architectures

Low-threshold:

I KID on a gm substrate for NEXUS/LBNL

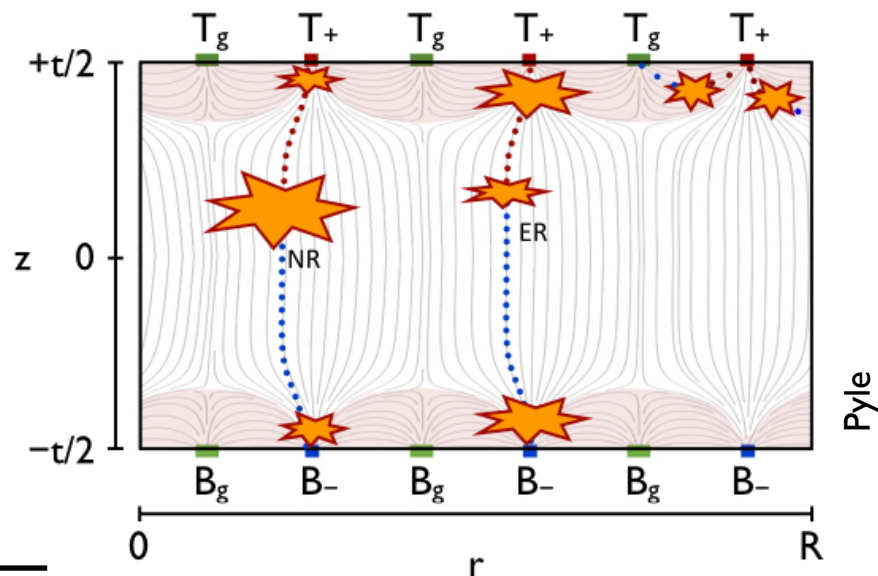


“piZIP”: Fine-grained phonon sensor enables:

Phonon-based fiducialization in z and r

NR/ER discr. via NTL phonon position

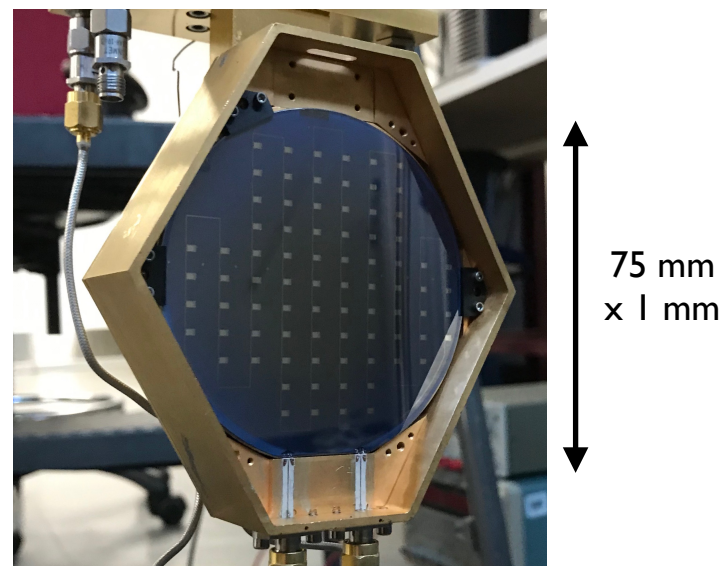
TAMU demo!



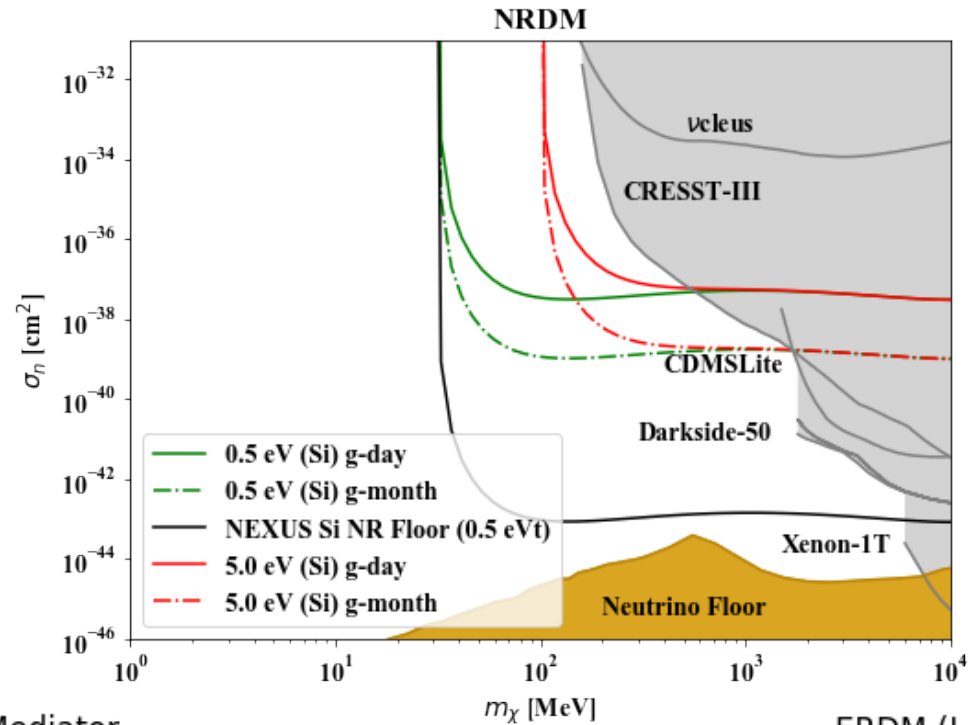
stage	σ_{pt}	
	low-threshold	piZIP
current (estimated)	20 eV	240 eV
single-KID optimized	1-7 eV	—
increase T_{qp} to 1 ms	0.3-2 eV	80 eV
quantum-limited amplifier	45-360 meV	25 eV
AlMn (T_c in K)	5-70 meV (0.1K)	5 eV (0.2K)
squeezed vacuum/ amplification	0.5-7 meV	—

Both architectures funded for development.: LBNL QIS + FNAL LDRD for low-threshold, DOE HEP DetRnD for piZIP, grad+postdoc fellowships

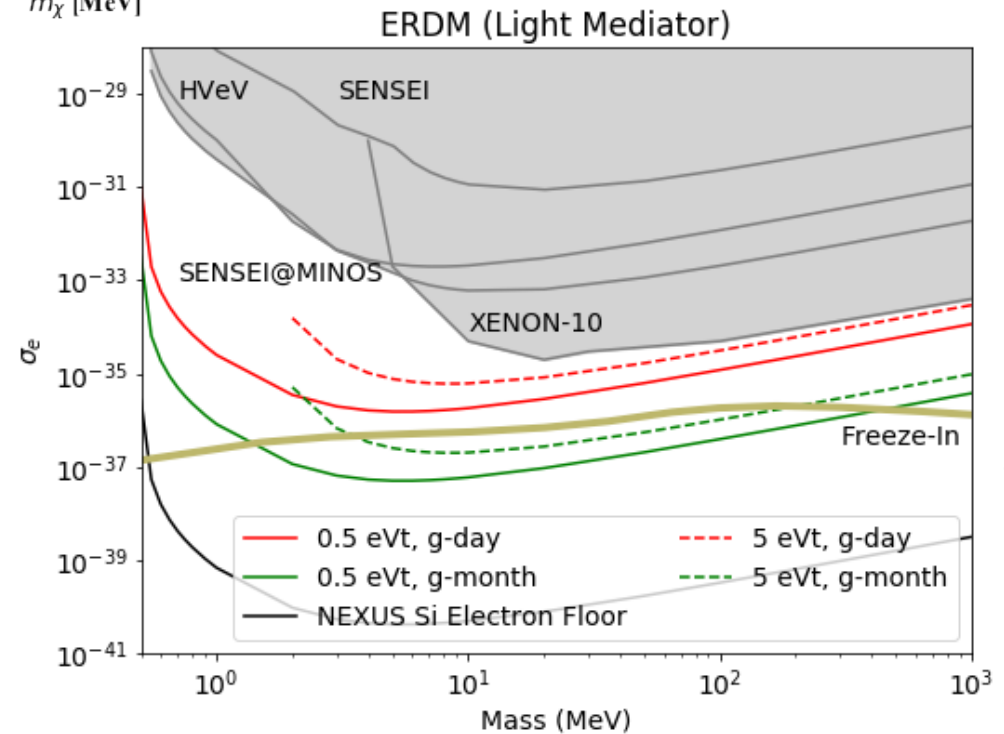
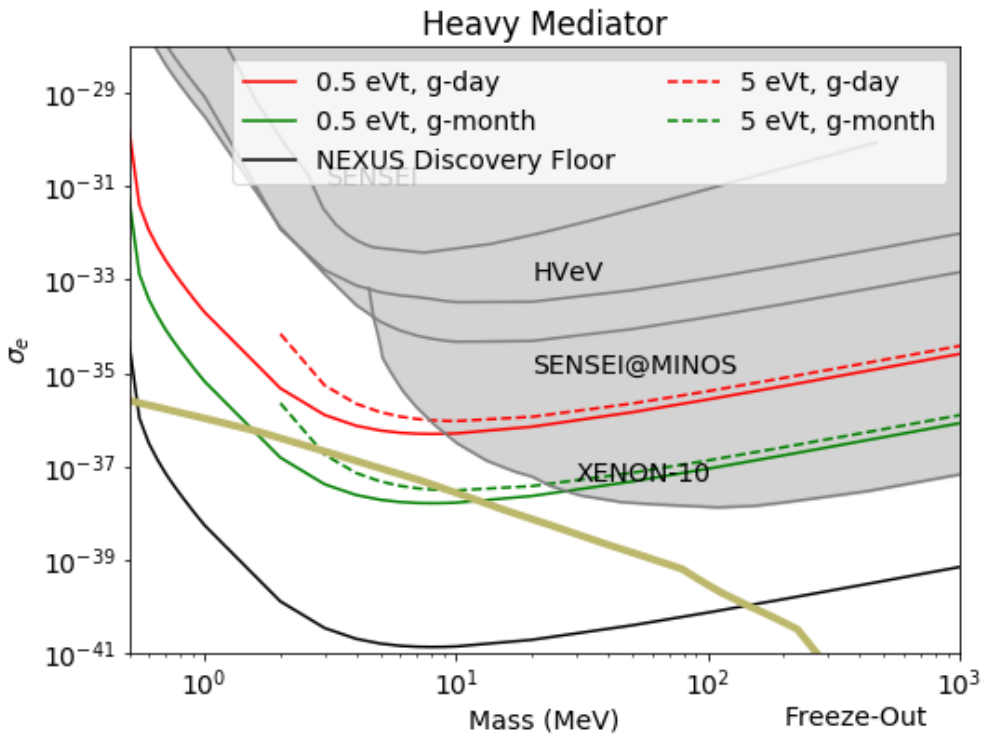
NR/ER discr. down to O(100) MeV!



Demonstration Runs Planned at NEXUS



Thresholds
(not σ_{pt}) are
shown



Limit plots from N. Kurinsky